Beating of the oscillations in the transport coe cients of a one-dim ensionally periodically modulated two-dim ensional

electron gas in the presence of spin-orbit interaction

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# Abstract

Transport properties of a two-dimensional electron gas (2D EG) are studied in the presence of a perpendicular magnetic eld B, of a weak one-dimensional (ID) periodic potential modulation, and of the spin-orbit interaction (SO I) described only by the Rashba term. In the absence of the modulation the SO Im ixes the spin-up and spin-down states of neighboring Landau levels into two new, unequally spaced energy branches. The levels of these branches broaden into bands in the presence of the modulation and their bandw if the oscillate with the eld B. Evaluated at the Ferm i energy, the n-th level bandw idth of each series has a minimum or vanishes at di erent values of the eld B. In contrast with the 1D-modulated 2D EG without SO I, for which only one at-band condition applies, here there are two at-band conditions that can change considerably as a function of the SO I strength and accordingly in uence the transport coe cients of the 2D EG. The phase and amplitude of the W eiss and Shubnikov-de H asas (SdH) oscillations depend on the strength . For sm all values of both oscillations show beating patterns. Those of the form er are due to the independently oscillating bandwidths whereas those of the latter are due to modi cations of the modulation strength. For strong values of the SdH oscillations are split in two.

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#### I. IN TRODUCTION

The magnetotransport of the 2DEG, subjected to periodic potential modulations, has attracted considerable experimental [1] and theoretical [2, 3] attention during the last two decades. For one-dimensional (1D) modulations novel oscillations of the magnetoresistivity tensor have been observed, at low magnetic elds B, distinctly di erent in period and temperature dependence from the usual Shubnikov-de H aas (SdH) ones observed at higher B. These novel oscillations, referred to as the W eiss oscillations, re ect the commensurability between two length scales: the cyclotron diameter at the Ferm i level  $2R_c = 2^{p} \frac{1}{2} \frac{1}{n_e} \frac{v^2}{c}$ , with  $n_e$  the electron density and 'c the magnetic length, and a the period of the potential modulation.

The emerging eld of spintronics brought into the fore the importance of spin-orbit interaction (SO I) in a variety of situations. It is in portant in the developm ent of spin-based transistors [4], possibly in future quantum computations [5], in an unexpected metal-to-insulator transition in 2D [6] hole gas, in spin-resolved ballistic transport [7], in A haronov-C asher experiments [8], in spin-galvanic [9] and spin valve [10] e ects, in the spin-Halle ect [11], etc. The e ect is in portant in inversely asymmetric bulk sem iconductor crystals, due to the internal crystal eld, as well in asym metrically con ned sem iconductor heterostructures. In k<sup>3</sup> the form er case the contributions to the spin splitting in the conduction band vary as a term and dominate in wide-gap structures [12] whereas in the latter vary as a k term, referred to as the R ashba term, and dom inate in narrow-gap structures [13]. The latter was con med by experiments that showed a zero-magnetic-eld spin splitting for carriers with nite momentum in a modulation-doped G aA s/A IG aA s hetero junction [14] as well as by magnetotransport measurements in a 2D hole system [15]. The explanation proposed by By chkov and Rashba [16] en ployed the Rashba spin-orbit Ham iltonian, in which the spin of nite-momentum electrons feels a magnetic eld perpendicular to the electron momentum in the inversion plane. A detailed account of magnetotransport of the 2DEG in the presence

of SO I but absence of m odulations appeared recently [17].

G iven the importance the SO I has acquired, one question that arises concerns its in unce on magnetotransport properties of a 2D EG in the presence of periodic potential modulations. So far we are aware of only the brief, classical study of Ref. [18]. Since some e ects of the modulations can be explained only quantum mechanically [3], it is of interest to

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reexam ine the problem quantum mechanically. This is the subject of this paper. We will consider only weak 1D m odulations and m ake use of our experience with them  $\beta$  and with the unm odulated 2DEG in the presence of SOI [17]. The main qualitative indings are as follows. The levels of the + and , unequally spaced energy branches, due to the SOI when the m odulation is absent, broaden into bands when the m odulation is present and their bandwidths oscillate with the eld B. Evaluated at the Ferm i energy, these bandwidths vanish at di erent values of the eld B and modify considerably the at-band condition and the transport coe cients as a function of the SOI strength . As a result, the phase and am plitude of the commensurability and SdH oscillations change when is varied. For sm all values of the form er show a beating pattern while for strong values of the latter are split in two.

In the next section we present the one-electron eigenfunctions and eigenvalues. A nalytical results for the conductivities are given in Sec. III and num erical results in Sec. IV. The last section contains a sum m ary and concluding remarks.

## II. EIGENFUNCTIONSAND EIGENVALUES

### A. A 2DEG in the presence of SOI and absence of potential modulation

We consider a 2DEG in the  $(x \ y)$  plane and a magnetic eld along the z direction. In the Landau gauge A = (0; B x; 0) the one-electron H am iltonian including the R ashba term reads

$$H_{0} = \frac{(p + eA)^{2}}{2m} + \frac{1}{2} [ (p + eA)] + \frac{1}{2} g_{B} B_{z}; \qquad (1)$$

where p is the momentum operator of the electrons, m is the electron mass, g the Zeem an factor, <sub>B</sub> the Bohr magneton, = (x; y; z) the Pauli spin matrices, and the strength of the SO I or R ashba parameter.

U sing the Landau wave functions without SO I as a basis, we can express the new eigenfunction in the form :

$$_{k_{y}}(\mathbf{r}) = e^{ik_{y}y} \sum_{n=0}^{x} (\mathbf{x} + \mathbf{x}_{c}) \sum_{c_{n}}^{c_{n}^{+}} = \frac{p}{L_{y}}$$
 (2)

Here  $_{n}(\mathbf{x}) = e^{-\mathbf{x}^{2} = 2\mathbf{l}_{c}^{2}} \mathbf{H}_{n}(\mathbf{x} = \mathbf{l}_{c}) = (^{p} - 2^{n} n \mathbf{l}_{c})^{1=2}$  is the harmonic oscillator function,  $\mathbf{l}_{c} = e^{p} - 2^{n} n \mathbf{l}_{c}$  and  $\mathbf{l}_{c} = e^{p} - 2^{n} n \mathbf{l}_{c}$ .

orbit is centered at  $x_c = l_c^2 k_y$ , n the Landau-level index, and j i the electron spin written as the row vector h j= (1; 0) if it's pointing up and (0; 1) if it's pointing down.

U sing these wave functions and Eq. (1) the eigenvalue problem  $H_0 = E$  leads to an in nite system of equations that can be solved exactly after decomposing it into independent system s of one or two equations [17]. The resulting eigenstates are labelled by a new quantum number s for the energy instead of n. For s = 0 there is one level, the same as the lowest Landau level without SO I, with energy

$$E_0^+ = E_0 = \sim !_c = 2 \quad g_B B = 2$$
 (3)

and wave function

$${}^{+}_{0}(\mathbf{k}_{y}) = e^{i\mathbf{k}_{y}y} {}_{0}(\mathbf{x} + \mathbf{x}_{c}) {}^{0}_{1} = {}^{p}\overline{\mathbf{L}_{y}}:$$
(4)

For s = 1;2;3;, there are two branches of levels, denoted by + and , with energies

$$E_{s} = s \cdot !_{c} \qquad [E_{0}^{2} + 2s^{-2} = I_{c}^{2}]^{1=2}$$
: (5)

The + branch is described by the wave function

$${}^{+}_{s} (k_{y}) = \frac{e^{ik_{y}y}}{E_{y}A_{s}} \begin{pmatrix} 0 & 1 \\ D_{s s 1} (x + x_{c}) \\ B_{s s} (x + x_{c}) \end{pmatrix} A;$$
(6)

and the one by

$${}_{s} (k_{y}) = \frac{e^{ik_{y}y}}{E_{y}A_{s}} \begin{pmatrix} 0 & 1 \\ s & (x + x_{c}) \\ D_{s} & (x + x_{c}) \end{pmatrix} A,$$
(7)

where  $A_s = 1 + D_s^2$  and  $D_s = (\frac{p}{2s} = l_c) = [E_0 + \frac{p}{E_0^2 + 2s^2 = l_c^2}]$ .

B. A 2DEG in the presence of SOI and of a 1D potential modulation

In the presence of a 1D periodic electric modulation, we consider the Ham iltonian

$$H = H_0 + V_0 \cos(K x);$$
(8)

with K = 2 = a and a the modulation period. For weak modulations the energy correction due to the term  $V_0 \cos(K x)$  is evaluated by rst-order perturbation theory. The results for the two branches are

$$E_{s}^{+} = s \sim !_{c} + E_{0}^{2} + 2s^{2} = I_{c}^{2} I_{c}^{1=2} + V_{0} e^{u=2} \cos(K x_{c}) D_{s}^{2} L_{s-1}(u) + L_{s}(u) = A_{s}; s = 0;1;$$
(9)

$$E_{s} = s \sim !_{c} \qquad E_{0}^{2} + 2s^{2} = I_{c}^{2}]^{1-2} + V_{0}e^{u-2} \cos(K x_{c}) [L_{s-1}(u) + D_{s}^{2}L_{s}(u)] = A_{s}; s = 1;2;$$
(10)

where  $u = 2 {}^{2}l_{c}^{2} = a^{2} = K {}^{2}l_{c}^{2} = 2$  and  $x_{c} = k_{y}l_{c}^{2}$ .  $L_{s}(u)$  is the Laguerre polynom ialand for s = 0Eq. (9) reduces to Eq. (3) as modilled by the perturbation correction. The width of the broadened levels of the two branches is given by twice the absolute value of the last term in Eqs. (9) and (10) without the  $\cos(K {}^{2}_{c}k_{y})$  factor and is denoted by 2j s j. s can be written in the compact form

$$s = V_0 e^{u=2} [L_{s \ 1=2} + D_s^2 L_{s \ 1=2}] = A_s;$$
(11)

with the upper signs pertaining to the + branch and the lower ones to the branch; obviously  $_{s}$  is not the same for the two branches. In contrast, without SO I we have only a single branch and a single bandwidth [3] and the eigenvalues are given, when the Zeem an term is neglected, by

$$E_{n} = (n + 1 = 2) \sim !_{c} + V_{0} e^{u = 2} \cos(K x_{c}) L_{n} (u)$$
(12)

with n the Landau-level index. This has consequences that will be detailed below.

As in the absence of SO I, the presence of the modulation broadens the discrete levels into bands. An important dimense with the situation in which the modulation is absent is that the diagonal matrix elements of the velocity operator now do not vanish. Using  $v_y = (1=\sim)0E_s (k_y)=0k_y$  their values are

$$v_{y}^{+} = 2V_{0}ue^{u=2} D_{s}^{2}L_{s-1}(u) + L_{s}(u) \sin(K x_{c}) = (~K A_{s});$$
 (13)

$$v_y = 2V_0 u e^{u=2} [L_{s-1}(u) + D_s^2 L_s(u)] \sin (K x_c) = (~K A_s):$$
 (14)

These non vanishing values lead to a non vanishing di usive conductivity whereas in the absence of the modulation this conductivity vanishes whether the SO I is present or not [17].

C on pared to the case without SO I, we have two contributions, one from Eq. (9) and one from Eq. (10), while for = 0 we have only one value given by

$$v_v = (2V_0 = -K) ue^{u-2} L_n (u) sin (K x_c):$$
 (15)

As a function of the magnetic eld B, these y contributions do not oscillate in phase due to the di erent dependence of the Laguerre polynom ials on B. This modi es mostly the di usive conductivity in the presence of the modulation and will be detailed in the following sections.

U sing the asymptotic expression of the Laguerre polynom ials for large s, we obtain  $_{s}$  /  $\cos(2^{p} \overline{su} = 4)$ . The Landau level indices \$ and s of the corresponding branches at the Ferm ienergy can be determined by the equations  $E_{s^{*}}^{+} = E_{s}^{-}$  and  $n_{e} = (s^{*} + s + 1) = (2 \ f_{c}^{2})$ , where  $n_{e}$  is the electron density. Then from the argument of  $\cos(2^{p} \overline{su} = 4)$  we obtain the at-band conditions

$$p - p - p - p - q = (2 - !_{c}) = (1 - 1 - 4) = 2$$
 (16)

with the upper (lower) sign corresponding to the + ( ) branch. Since the cyclotron radius at the Ferm ienergy is  $R_c = l_c^p \frac{1}{2s + 1}$ , Eq. (16) can be written as  $2R_c = a = i$  1=4 with  $R_c = R_c^0 = -l_c$  and  $R_c^0$  the cyclotron radius without SO I or K ( $k_F = k$ ) $l_c^2 = (i = 1=4)$  with  $k_F = \frac{p}{2} \frac{1}{n_e}$ , and  $k = m = -^2$ . The same result has been obtained in Ref. [18] by a purely classical treatment. The fact that now we have two at-band conditions, as opposed to one for = 0, leads to oscillations with two di erent frequencies and consequently to beating patterns that will be shown in Sec. IV. Explicitly, writing Eq. (16) again for  $i! = a = [2 - (k_F = k)]$  and  $= a = [2 - (k_F + k)]$ .

# III. CONDUCTIVITIES

For weak electric elds E, i.e., for linear responses, and weak scattering potentials the expressions for the direct current (dc) conductivity tensor , in the one-electron approximation, reviewed in Ref. [21], reads =  $^{d} + ^{nd}$  with ; = x;y;z. The term s  $^{d}$  and  $^{nd}$  stem from the diagonal and nondiagonal part of the density operator b, respectively, in a given basis and hJ i = Tr(bJ) = E. In general, we have  $^{d} = ^{dif} + ^{col}$ . The term

 $^{\rm dif}$  describes the di usive m otion of electrons and the term  $^{\rm col}$  the collision contributions or hopping. The form er is given by

$$dif = \frac{e^2 X}{S_0} \quad f(E_s) [1 \quad f(E_s)] \quad (E_s) v v; \qquad (17)$$

where (s; ;k) denotes the quantum numbers, v = h jv j i is the diagonal element of the velocity operator v, and f (") the Ferm iD irac function. Further, ( $E_s$ ) is the relaxation time for elastic scattering, =  $1=k_B T$ , and  $S_0$  is the area of the system.

The term <sup>col</sup> can be written in the form

$$\sum_{yy}^{\infty 1} = \frac{e^2}{2S_0} X \begin{bmatrix} z & z & z \\ d & d \end{bmatrix} d^{(0)} [" & E_s(k_x)] ["^0 & E_{s^0}(k_x^0)]f(") [1 & f("^0)]W \circ (";"^0) (y & y_0)^2;$$
(18)

where y = h jyj i;  $W \circ ("; "^0)$  is the transition rate. For elastic scattering by dilute in purities, of density  $N_{I}$ , we have

$$W \circ (";"^{0}) = \frac{2 N_{I}}{\sim S_{0}}^{X} \quad \text{if } (q) \text{if } = (u) \text{if } (" )_{k_{x};k_{x}^{0} q_{x}}; \quad (19)$$

where  $u = l_c^2 q^2 = 2$  and  $q^2 = q_k^2 + q_y^2$ . U (q) =  $(e^2 = 2_0) = (q + k_s)$  is the Fourier transform of the screened in purity potential with the static dielectric constant, 0 the dielectric perm ittivity, and  $k_s$  the screening wave vector.

The di usion contribution given by Eq. (17) becomes

$$\frac{dif}{yy} = \frac{e^2}{h} \frac{4 u^2}{K} \frac{X}{s} \frac{2 a^{-2l_c^2}}{a^2} dk_y (s)^2 \sin^2 (K l_c^2 k_y) f(E_{n,k_y}) [1 f(E_{n,k_y})]$$
(20)

with s = s given by Eq. (11). The related contribution  $dif_{xx}$  is zero since the velocity  $v_x$  vanishes.

For weak potential modulations we can neglect Landau-level mixing, i.e., we can take  

$$s^{0} = s$$
. Then noting that  $\sum_{xx}^{\infty 1} = \sum_{yy}^{\infty 1} \sum_{q}^{P} = (S_{0}=2) \sum_{0}^{R_{1}} qdq = (S_{0}=2 \frac{1}{c}) \sum_{0}^{R_{1}} du$ , and  
 $P_{k_{x}} = (S_{0}=2 \frac{1}{c})$ , the collisional contribution given by Eq. (18) takes the form  
 $\sum_{yy}^{\infty 1} = \frac{e^{2} N_{I}}{2A_{0}} \sum_{s; k_{y}}^{Z} \int_{0}^{1} du f_{ss}(u) \int_{1}^{2} u \int_{1}^{2} du f_{ss}(u) \int_{1}^{2} u \int_{1}^{1} du f_{ss}(u) \int_{1}^{2} u \int_{1}^{2} du f_{ss}(u) \int_{1}^{2} du f_{ss}(u)$ 

where

$$F_{ss}(u)^{2} = fL_{s-1}(u) + D_{s}^{2}L_{s}(u)g^{2}e^{-u} = A_{s}^{2};$$
 (22)

$$F_{ss}^{+}(u)^{2} = fD_{s}^{2}L_{s-1}(u) + L_{s}(u)g^{2}e^{-u} = A_{s}^{2}$$
: (23)

The exponential e<sup>u</sup> favors small values of u. A ssum ing  $b = k_s^2 l_c^2 = 2$  u we may neglect the term  $2u = l_c^2$  in the expression for U  $\begin{pmatrix} p \\ 2u = l_c^2 \end{pmatrix}$  and de ne  $U_0 = U(0)$ . We then obtain

$$\sum_{yy}^{col} = \frac{e^2}{h} \frac{N_{I} U_0^2}{a} X^{2} \sum_{a=2I_c^2}^{a=2I_c^2} dk_y I_s f(") [1 f(")]; \qquad (24)$$

where

$$I_s = [(2s \ 1)D_s^4 \ 2sD_s^2 + 2s \ 1]=A_s^2$$
: (25)

The impurity density  $N_{I}$  determ ines the Landau Level broadening =  $W_{0}(";"^{0}) = \sim$ . Evaluating  $W_{0}(";"^{0}) = \sim$  in the u ! 0 lim it without taking into account the SO I, we obtain  $N_{I} = 4 [(2_{0} = e^{2})]^{2} = \sim$ .

The Hall conductivity <sup>nd</sup><sub>xy</sub> is given by

$$\sum_{xy}^{nd} = \frac{2i e^2}{S_0} X_{,0} f(E) [1 f(E^0)] < j v_x j^0 > < 0 j v_y j > \frac{1 e^{(E - E^0)}}{(E - E^0)^2}; 0 \in (26)$$

The resistivity tensor is given in terms of the conductivity tensor upon using the standard expressions xx = yy=S, yy = xx=S, yx = xy = yx=S, where S = xx yy = xy yx.

### IV. NUMERICAL RESULTS

In this section we present num erical results for the bandwidth and the two conductivities given by Eqs. (20) and (23) for various values of the SO I strength , of the modulation strength  $V_0$  and period a, of the electron density  $n_e$ , and of the tem perature T. W emeasure in units of  $_0 = 10^{-11}$  eVm,  $n_e$  in units of  $n_0 = 10^{-11}$  eVm are units of  $n_0 = 10^{-11}$  eVm.

In units of  $_0 = 10$  eV m,  $n_e$  in units of  $n_0 = 10$  = and , and use the electron mass of  $10 = 0.05m_0$  with  $m_0$  the free-electron mass.

In Fig. 1 we plot  $_{s}$ , given by Eq. (11) and directly related to the bandwidth 2j  $_{s}$  j at the Ferm i level, as a function of the magnetic eld B in the upper panels and as a function of the inverse magnetic eld 1=B in the lower panels. The other parameters are a = 3500A, T = 2 K,  $n_{e} = 3n_{0}$ , and  $V_{0} = 0.5 \text{ m eV}$ . We plot  $_{s}$  and not 2j  $_{s}$  jso that the oscillations are seen m ore clearly. Comparing the = 0 panelwith the  $\neq 0$  ones, we see clearly, for  $\neq 0$ , the contributions from the + and = 0 branches. The large-am plitude oscillations, for low B in the upper panels and for high 1=B in the lower panels, are the W eiss oscillations whereas

the step-like behavior on the right side of the upper panels is due to the small-amplitude SdH ones. On the scale used the latter are barely visible on the very left side in the lower panels. The phase shift between the oscillations of  $_{s}^{+}$  and  $_{s}^{-}$  and their slightly dimentified frequencies described by Eq. (16) lead to the beating patterns of the conductivities shown below. For example, for  $= 2_{0}$  the oscillations of the bandwidth  $2j_{s}j$  given after Eq. (16), have a period  $^{+} = 2:14$  T  $^{-1}$  in the + branch and a period = 1:76 T  $^{-1}$  in the branch.

In Fig. 2 we plot the conductivities vs the inverse of the magnetic eld B for di erent values of and a shorter modulation period a = 800 A. The upper curve is the collisional conductivity, given by Eq. (23), and the lower one the di usive conductivity, given by Eq. (20). Notice the absence of a beating pattern for = 0 and its development for  $\notin 0$ . For nite , the longer-period beating pattern of the W eiss oscillations is observed in the di usive curves and the shorter-period beating pattern of the SdH oscillations [17] in the collisional curves. The reason is that at low magnetic elds and low temperatures the W eiss oscillations dom inate the di usive conductivity. In the form er the energy correction due to the modulation, given by Eqs. (9)-(10), enters mainly the square of  $v_y$  and the argument of the Ferm i function, cf. Eqs. (17), (20), whereas in the latter it enters essentially only through the argument of the Ferm i function, cf. Eqs. (18), (24).

To see the oscillations shown in Fig. 2 m ore clearly, we plot the conductivities vs lling factor nh=eB in Fig. 3 for =  $_0$  and  $n_e = 3n_0$ . As can be seen, the collisional conductivity (upper curve) shows a beating pattern of the SdH oscillations resulting from the di erent Landau-level separations in the + and spin branches. The index s at the Fermi energy is expressed approximately as s = ( $n_e \sim m^2 \frac{p}{2 n_e} = \sim$ )=eB. The resulting period of the beating pattern, measured in units of inverse magnetic eld, is  $2 \sim k_F = e \text{ or } 0.85\text{ T}^{-1}$  in Fig. 3. We notice that a transition from conductivity maxim a at even lling factors to conductivity maxim a at odd lling factors occurs between adjacent wraps of the SdH oscillations. This can be understood by checking the DOS of the system. As shown in Fig. 4, when the subband broadening is comparable to the subband separation, a beating pattern appears in the DOS, with SOI present and modulation absent, and each DOS peak corresponds to one pair of spin levels. Because the spin-up and spin-down levels have di erent separations, there is one unpaired spin level at each node of the beating pattern. As a result, in one wrap of the

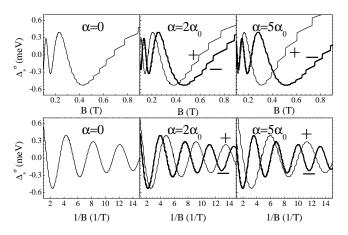


FIG.1: The quantity  $_{\rm s}$  of Eq. (11) vs m agnetic eld B (upper panels) and vs inverse m agnetic eld 1=B (low er panels), at the Ferm i level, for di erent values of the strength . The m odulation period is a = 3500A and the m odulation strength V<sub>0</sub> = 0.5m eV.

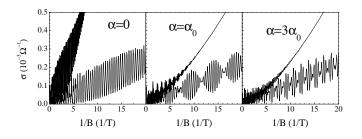


FIG.2: Conductivities vs inverse magnetic eld B for di erent values of with a = 800 A, T = 1 K,  $n_e = 3n_0$ , and  $V_0 = 0.3 \text{ m eV}$ . The upper (lower) curves show the collisional (di usive) contribution.

DOS oscillations there is an even number of levels below each pair and the DOS has a peak at odd lling factors, while in the next wrap there is an odd number of levels below each pair and the DOS has a peak at even lling factors. When the Ferm i energy passes through the

branches and the DOS is as described above, the collisional conductivity shows a beating pattern with an even-odd lling factor transition. A though here the modulation is present, it is very weak and leaves the oscillations of the collisional conductivity nearly intact. A complementary way of seeing how the beating pattern is formed, is to plot separately  $^{\infty l;}$  and  $^{\infty l;+}$ . Both contributions oscillate with slightly dimentifications and their sum

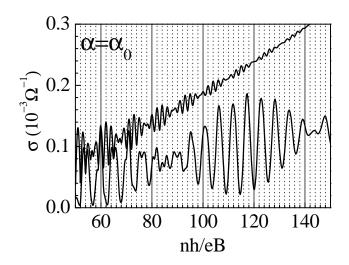


FIG.3: Conductivities vs lling factor nh=eB for the panel =  $_0$  of Fig. 2. The dashed vertical lines show the even lling factor values and the curves are marked as in Fig. 2.

shows the beating pattern of Fig. 3. The period of this pattern, in units of inverse of magnetic eld, is ea= $4 \sim k$  or  $4.63T^{-1}$  in Fig. 3. A similar even-odd lling factor transition was also observed for strong modulations, which make the Landau levels overlap, in the absence of SO I and was explained by the behavior of the corresponding DOS [22]. The di usive conductivity (lower curve) shows mainly a beating pattern of the W eiss oscillations since here the SdH oscillations are very weak.

Above we observed a beating pattern in the SdH and W eiss oscillations occurring, respectively, in the collisional and di usive conductivities, vs lling factor when varying the magnetic eld at a xed electron density. If we vary the electron density and x the magnetic eld B, the beating pattern of the SdH oscillations holds because it corresponds to the Ferm i energy passing through the DOS with beating pattern. However, we do not observe a beating pattern in the W eiss oscillations. This can be explained by Eq. (16), from where we see that, for xed B, the bandwidths of the two series of spin levels oscillate with the same frequency as a function of the electron density  $n_e$  though with di erent phases. For a system without the potential modulation, the di usive conductivity disappears and we observe only a beating pattern of the SdH oscillations in the collisional conductivity.

In Fig. 5 we plot again the conductivities vs the inverse of the magnetic eld B for

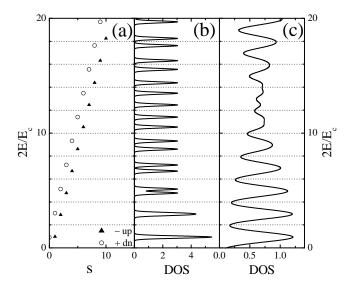


FIG.4: (a) Subband energy vs index s in the absence of modulation. The DOS vs energy is shown in (b) for subband broadening = 0.1 meV and in (c) for = 0.5 meV. When E is the Ferm i energy the quantity  $2E = E_c$  with  $E_c = \sim !_c$  is approximately the lling factor.

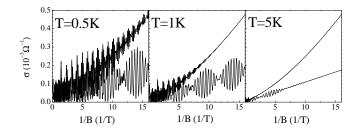


FIG. 5: C onductivities vs inverse magnetic eld B for di erent tem peratures with  $=_0$  and  $n_e = 3n_0$ . The upper (lower) curves show the collisional (di usive) contribution.

di erent values of the tem perature,  $= _0$ ,  $n_e = 3n_0$ , and  $V_0 = 0.3$  m eV. The two curves are marked as in Fig. 2. Notice that beating pattern exists for all tem peratures but the oscillation amplitude decreases with increasing tem perature and nearly disappears at T 5 K for the density and SO I strength used.

In Fig. 6 we plot the conductivities vs m agnetic eld B, for rather strong values of B, and di erent . The tem perature is T = 1K. The dotted (solid) curves show the collisional

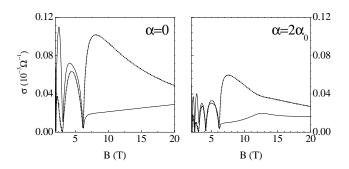


FIG.6: Conductivities vsm agnetic eld B for two di erent values of . The tem perature is T = 1Kand the density  $n_e = 3n_0$ . The dotted (solid) curves show the collisional (di usive) conductivity.

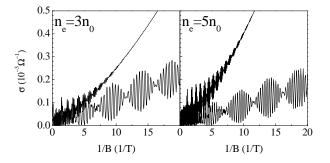


FIG.7: Conductivities vs inverse m agnetic eld B for di erent densities,  $= _0$ , and tem perature T = 1 K. The upper (lower) curves show the collisional (di usive) conductivity.

(di usive) conductivity. The SO I splits each Landau subband and reduces the DOS inside it. As a result, a reduction in the oscillation amplitude and a splitting of the (SdH) oscillations are observed in the = 2  $_0$  panel compared with the = 0 one. For the high magnetic

elds involved here, the period of the W eiss oscillations is very long and both the di usive and collisional conductivity curves show the SdH oscillations with the same phase.

In Fig. 7 we plot the conductivities vs magnetic eld B for di erent densities,  $=_0$ , and temperature T = 1K. Again the two curves are marked as in Fig. 2. Notice how increasing the density and thus changing the position of the Ferm i level relative to those of the + and branches closest to it modi es the beating pattern.

In Fig. 8 we plot the conductivities vs magnetic eld B for di erent . The density is  $n_e = 3n_0$  and the temperature T = 2 K. The upper (lower) curves are the collisional

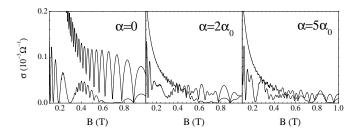


FIG.8: Conductivities vsm agnetic eld B for di erent . The density is  $n_e = 3n_0$ , the modulation period a = 3500A, and the temperature T = 2 K. The upper (lower) curves show the collisional (di usive) conductivity.

(di usive) contributions. The di usive curve shows mainly the W eiss oscillations at low B and at high B the short-period SdH oscillations in addition to the long-period W eiss oscillations. The collisional curve shows clearly the SdH oscillations for = 0 and a beating pattern of the SdH oscillation for nite .

We now address the issue of the Hall conductivity  $\frac{nd}{xy}$ . In the absence of modulation and presence of SO I, it has been evaluated in Ref. [17] for rather strong elds B 1 T and shows two series of quantum Hall plateaus, for strong (  $10_{0}$ , corresponding to the two branches developed due the SO I. The 1D modulation removes the ky degeneracy of the Landau levels  $E_s$  and broadens them into bands with eigenvalues  $E_{s,k_v}$ . From Eq. (26) we see that this may a ect the Hall conductivity at weak magnetic elds when the broadening  $_{\rm s}$  is comparable to the energy ~!  $_{\rm c}$ . In the presence of modulation and absence of SO I, it has been evaluated in Ref. [3] for weak elds B 1 T and shows very smallamplitude oscillations expressed mainly through the energy di erence between the n and 1 Landau levels. Here the interest is in the region of weak elds B 1 T for which n the W eiss oscillations appear. Despite the fact that s is comparable to ~!, it exhibits again very small-amplitude oscillations so far not observed for weak modulations [23]. If we neglect these oscillations, it is approximately given by  $~^{\rm nd}_{_{\rm XV}}$ ne=B.

Experimentally one usually measures the resistivity . Using the expressions given at the end of Sec. III for ,  $_{xy}^{nd}$  ne=B, and the results for  $_{yy}$  and  $_{xx}$ , we show in Fig. 8 the resistivities divided by the magnetic eld  $_{xx}$ =B, for =  $_{0}$  (upper panel) and = 3  $_{0}$  (lower panel), as a function of the magnetic eld for a system with  $n_{e} = 3n_{0}$  and otherwise

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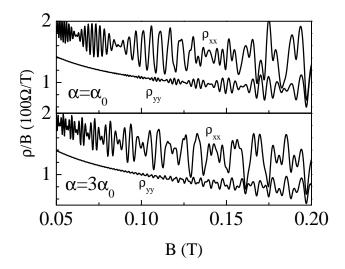


FIG.9: Resistivities divided by the eld B, xx = B and yy = B, vs eld B for = 0 (upper panel) and  $= 3_0$  (lower panel). The other parameters are the same as in Fig. 2.

the same parameters as in Fig. 7. For = 0 and in the low – eld region, in which the SdH oscillations are absent, a beating pattern of the W eiss oscillations is clearly observed in the xx curve. The yy curve exhibits a beating pattern only for the SdH oscillations since they result only from collisional current contributions and the W eiss oscillations are very weak as the di usive contributions to yy / xx vanish. For  $= 3_0$  though the beating patterns dhange: that of the W eiss oscillations, when discernible in xx, becomes shorter and that of the SdH oscillations in yy disappears. For completeness it should be mentioned, though not shown, that for = 0 there are no beating patterns in either the W eiss [3] or SdH [17] oscillations.

### V. CONCLUDING REMARKS

We evaluated quantum mechanically the dc conductivities of a 2DEG in the presence of SOI of strength , of a norm alm agnetic eld B, and of a weak 1D potential modulation of strength  $V_0$  and of period a. The SOI splits the Landau levels, for = 0, in two unequally spaced energy branches. As in the absence of SOI, the modulation broadens the levels of these branches into bands and their bandwidths oscillate independently with the eld B. This gives rise to two at-band conditions, instead of one for = 0, and to the beating patterns of the W eiss oscillations. As for the SdH oscillations, their beating patterns for

weak are nearly independent of the modulation, at least as long as the latter is weak, and agree with those of Ref. 17 obtained in the absence of modulation. However, for strong an additional structure is obtained and the SdH oscillations split in two, cf. Fig. 6. We also noticed the even-odd lling factor transition in the SdH oscillations and explained it with the help of the broadened DOS.A sim ilar observation was made in Ref. 22 for strong modulations and was explained by the corresponding DOS.

Regarding the W eiss oscillations the results for the di usive conductivity agree, as expected, for the relevant weak magnetic elds and high quantum numbers s, with those of the classical evaluation of R ef. [18]. However, the results for the collisional conductivity could not be obtained by a classical treatment and, to our know lege, are new. It is well known that this collisional or hopping conductivity describes the SdH oscillations which cannot be treated classically. This explains their absence from R ef. [18] and their modi cation for strong as well as for strong B, cf. F ig. 6, presented here.

For weak both conductivities exhibit beating patterns. Those of the di usive conductivity pertain to the W eiss oscillations and are due to the two independent frequencies involved in the bandwidths of the + and branches created by the SO I whereas those of the collisional conductivity pertain to the SdH oscillations and have a similar explanation though the two frequencies involved here are not those of the bandwidths, see the discussion of Fig. 3. As we saw though, these patterns weaken or disappear rather quickly upon increasing the tem perature or the strength .0 n the electron density  $n_e$  though, they appear to have a rather weak dependence, cf. Fig. 7, at least as long as  $n_e$  falls in the range of the usual experimental densities of a 2D EG.

We are not aware of any directly relevant experimental work. We hope though that the ndings described above will motivate experiments in which the magnetoresistivities along the x and y directions could be measured in a weakly modulated 2DEG in the presence of SOI. For a 1D modulation along the x direction, the di usive and collisional contributions to the conductivity can be obtained separately using the relations  $_{yy} = \frac{dif}{yy} + \frac{col}{yy}$  and  $_{xx} = \frac{col}{xx}$ . Combining them with the standard relations given after Eq. (26), gives the magnetoresistivities.

#### A cknow ledgm ents

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